



# Heterojunction Bipolar Transistor Technology (InGaP HBT)

## Broadband High Linearity Amplifier

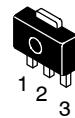
The MMG3015NT1 is a general purpose amplifier that is internally input and output matched. It is designed for a broad range of Class A, small-signal, high linearity, general purpose applications. It is suitable for applications with frequencies from 0 to 6000 MHz such as cellular, PCS, BWA, WLL, PHS, CATV, VHF, UHF, UMTS and general small-signal RF.

### Features

- Frequency: 0–6000 MHz
- P1dB: 20.5 dBm @ 900 MHz
- Small Signal Gain: 15.5 dB @ 900 MHz
- Third Order Output Intercept Point: 36 dBm @ 900 MHz
- Single 5 Volt Supply
- Active Bias Control
- Internally Matched to 50 Ohms
- Cost-effective SOT-89 Surface Mount Package
- In Tape and Reel. T1 Suffix = 1,000 Units, 12 mm Tape Width, 7 inch Reel.

**MMG3015NT1**

**0–6000 MHz, 15.5 dB  
20.5 dBm  
InGaP HBT**



**CASE 1514-02, STYLE 1  
SOT-89  
PLASTIC**

**Table 1. Typical Performance (1)**

Characteristic	Symbol	900 MHz	2140 MHz	3500 MHz	Unit
Small-Signal Gain (S21)	$G_p$	15.5	14.5	12.5	dB
Input Return Loss (S11)	IRL	-15	-19	-19	dB
Output Return Loss (S22)	ORL	-13	-9	-7	dB
Power Output @1dB Compression	P1dB	20.5	20.5	18.5	dBm
Third Order Output Intercept Point	OIP3	36	33.5	30.5	dBm

1.  $V_{CC} = 5$  Vdc,  $T_A = 25^\circ\text{C}$ , 50 ohm system.

**Table 2. Maximum Ratings**

Rating	Symbol	Value	Unit
Supply Voltage	$V_{CC}$	7	V
Supply Current	$I_{CC}$	300	mA
RF Input Power	$P_{in}$	12	dBm
Storage Temperature Range	$T_{stg}$	-65 to +150	$^\circ\text{C}$
Junction Temperature (2)	$T_J$	150	$^\circ\text{C}$

2. For reliable operation, the junction temperature should not exceed  $150^\circ\text{C}$ .

**Table 3. Thermal Characteristics**

Characteristic	Symbol	Value (3)	Unit
Thermal Resistance, Junction to Case Case Temperature $95^\circ\text{C}$ , 5 Vdc, 95 mA, no RF applied	$R_{\theta JC}$	41.5	$^\circ\text{C}/\text{W}$

3. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.freescale.com/rf>. Select Documentation/Application Notes - AN1955.

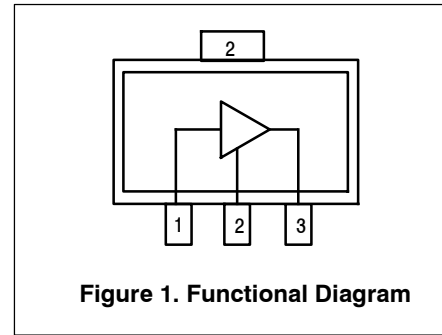
**Table 4. Electrical Characteristics** ( $V_{CC} = 5$  Vdc, 900 MHz,  $T_A = 25^\circ\text{C}$ , 50 ohm system, in Freescale Application Circuit)

Characteristic	Symbol	Min	Typ	Max	Unit
Small-Signal Gain (S21)	$G_p$	14	15.5	—	dB
Input Return Loss (S11)	IRL	—	-15	—	dB
Output Return Loss (S22)	ORL	—	-13	—	dB
Power Output @ 1dB Compression	P1dB	—	20.5	—	dBm
Third Order Output Intercept Point	OIP3	—	36	—	dBm
Noise Figure	NF	—	5.6	—	dB
Supply Current (1)	$I_{CC}$	80	95	120	mA
Supply Voltage (1)	$V_{CC}$	—	5	—	V

1. For reliable operation, the junction temperature should not exceed  $150^\circ\text{C}$ .

**Table 5. Functional Pin Description**

Pin Number	Pin Function
1	RF <sub>in</sub>
2	Ground
3	RF <sub>out</sub> /DC Supply

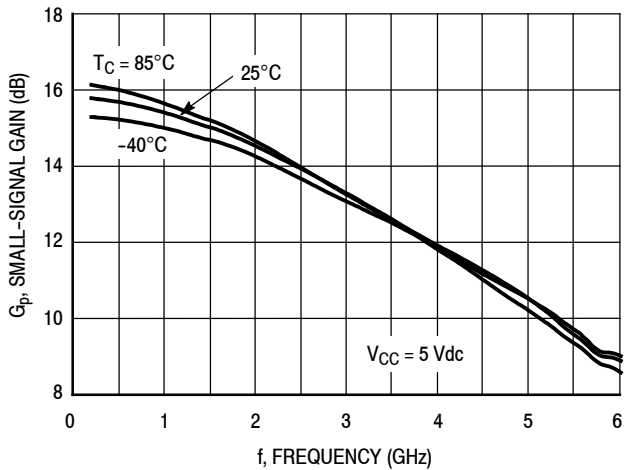
**Table 6. ESD Protection Characteristics**

Test Methodology	Class
Human Body Model (per JESD 22-A114)	1C
Machine Model (per EIA/JESD 22-A115)	A
Charge Device Model (per JESD 22-C101)	IV

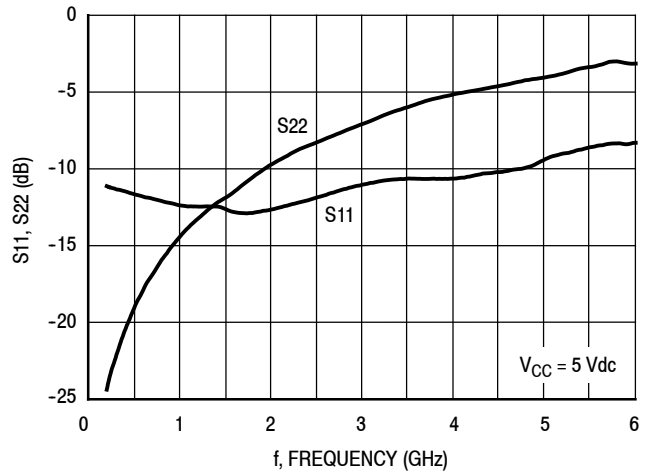
**Table 7. Moisture Sensitivity Level**

Test Methodology	Rating	Package Peak Temperature	Unit
Per JESD 22-A113, IPC/JEDEC J-STD-020	1	260	°C

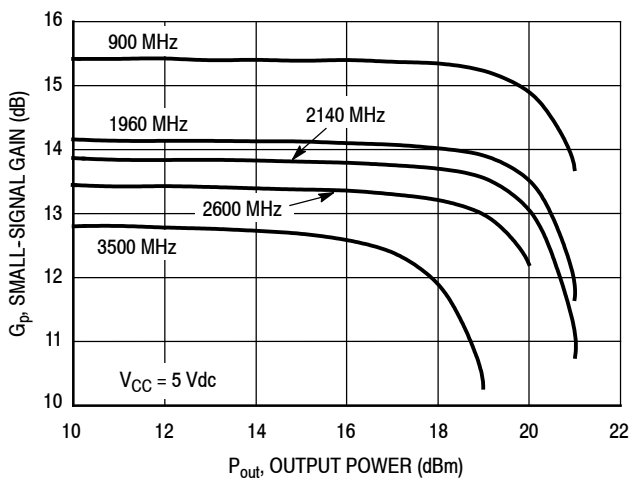
## 50 OHM TYPICAL CHARACTERISTICS



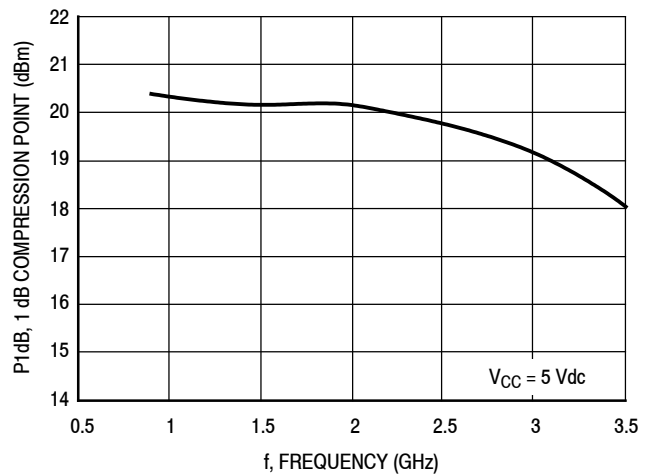
**Figure 2. Small-Signal Gain (S21) versus Frequency**



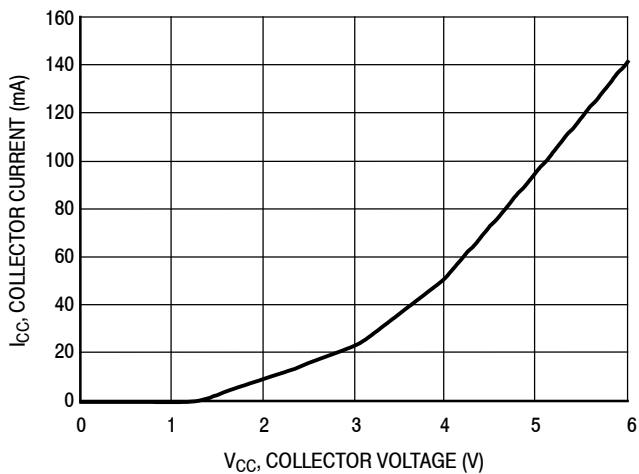
**Figure 3. Input/Output Loss versus Frequency**



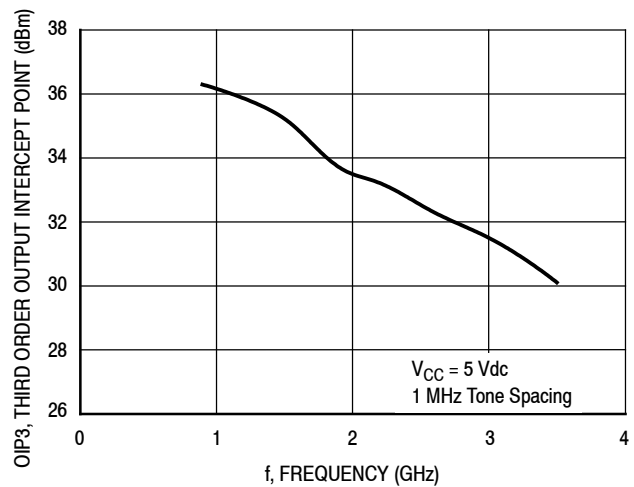
**Figure 4. Small-Signal Gain versus Output Power**



**Figure 5. P1dB versus Frequency**

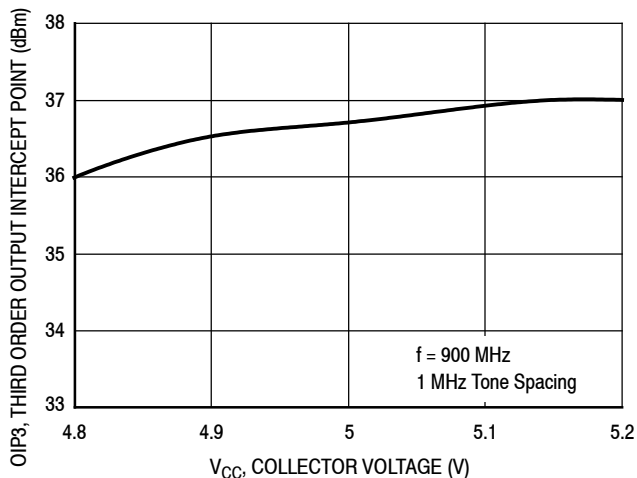


**Figure 6. Collector Current versus Collector Voltage**

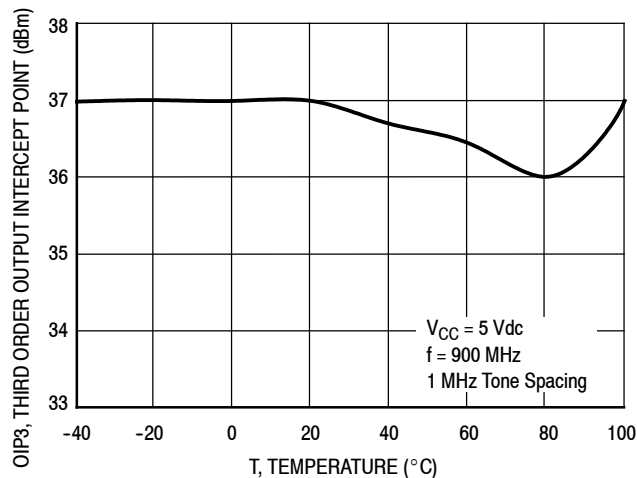


**Figure 7. Third Order Output Intercept Point versus Frequency**

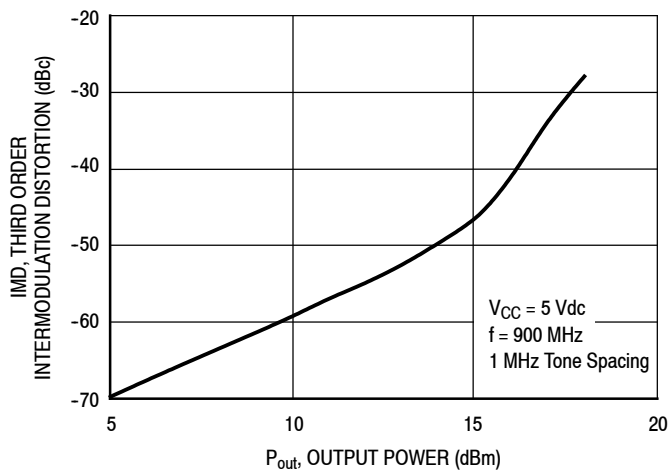
## 50 OHM TYPICAL CHARACTERISTICS



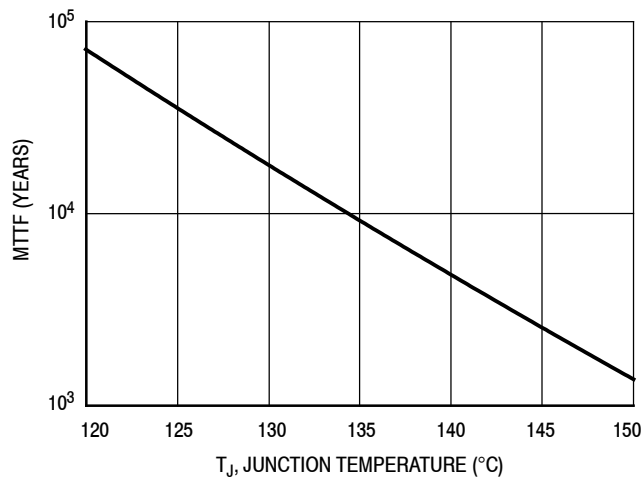
**Figure 8. Third Order Output Intercept Point versus Collector Voltage**



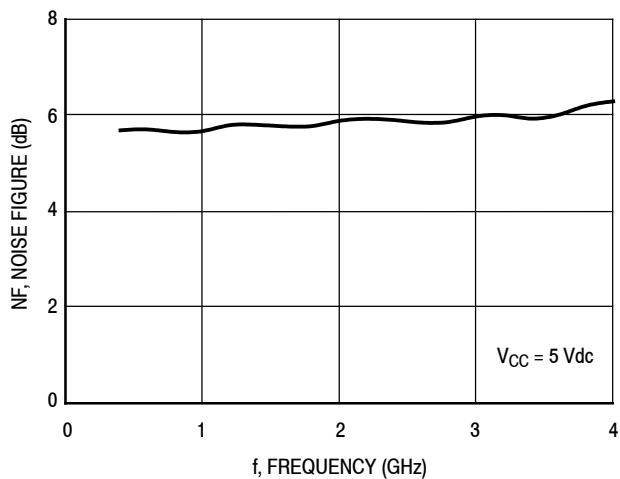
**Figure 9. Third Order Output Intercept Point versus Case Temperature**



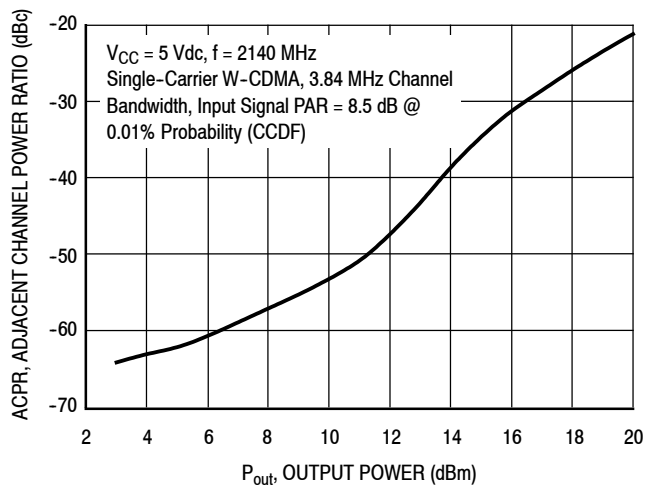
**Figure 10. Third Order Intermodulation Distortion versus Output Power**



NOTE: The MTTF is calculated with  $V_{CC} = 5 \text{ Vdc}$ ,  $I_{CC} = 95 \text{ mA}$   
**Figure 11. MTTF versus Junction Temperature**

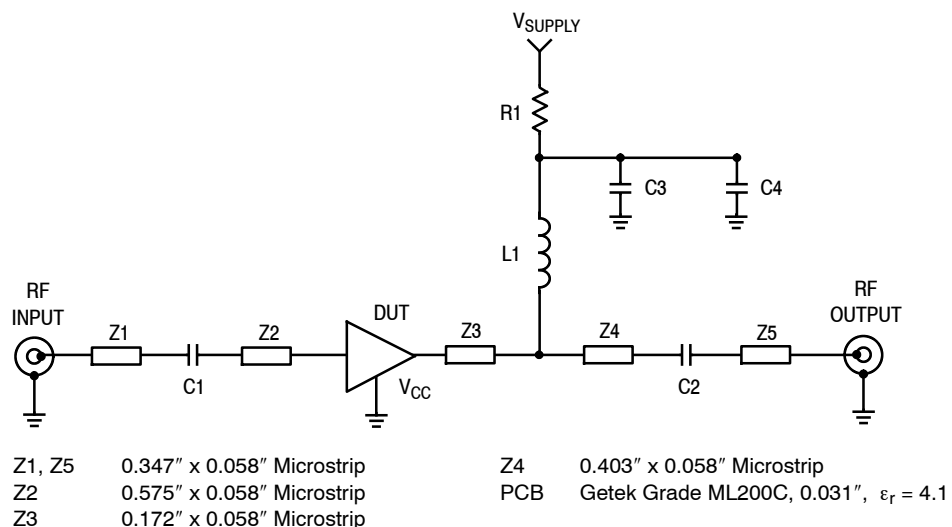


**Figure 12. Noise Figure versus Frequency**

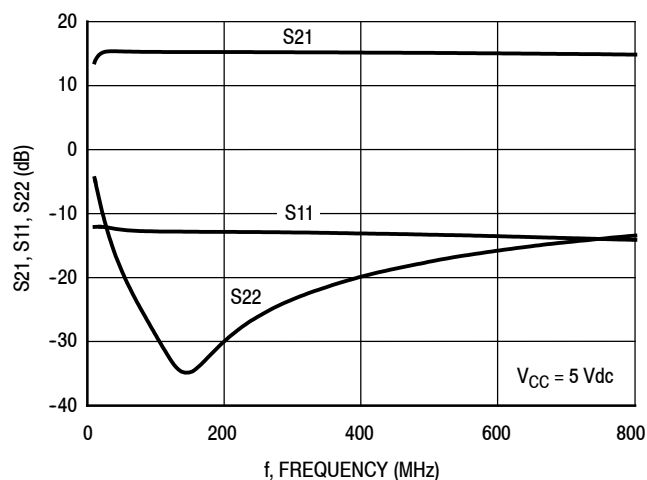


**Figure 13. Single-Carrier W-CDMA Adjacent Channel Power Ratio versus Output Power**

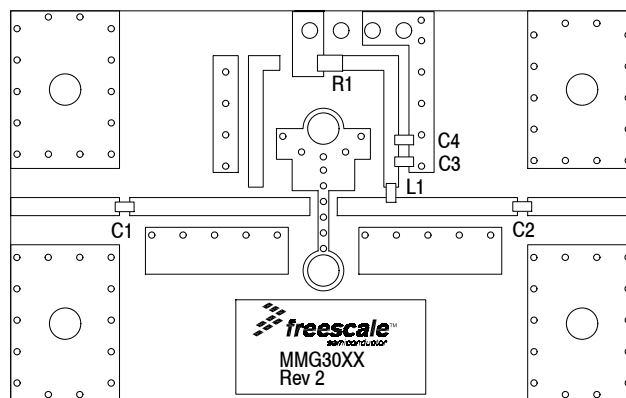
## 50 OHM APPLICATION CIRCUIT: 40-800 MHz



**Figure 14. 50 Ohm Test Circuit Schematic**



**Figure 15. S21, S11 and S22 versus Frequency**

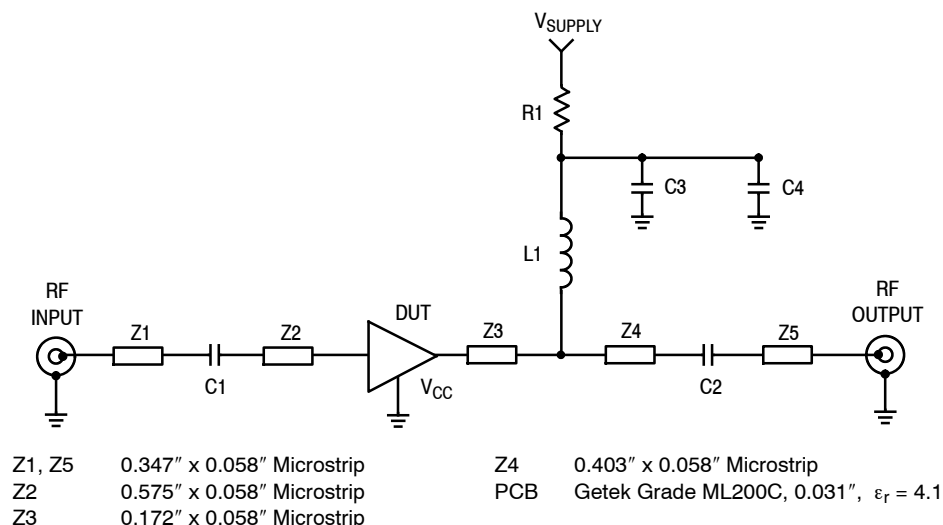


**Figure 16. 50 Ohm Test Circuit Component Layout**

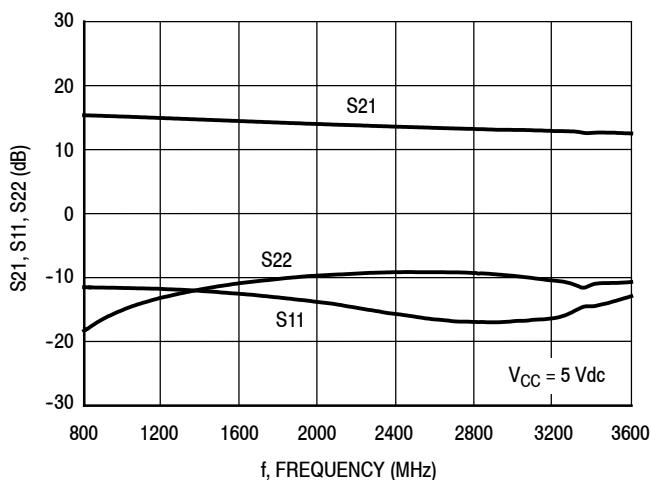
**Table 8. 50 Ohm Test Circuit Component Designations and Values**

Part	Description	Part Number	Manufacturer
C1, C2	0.01 $\mu\text{F}$ Chip Capacitors	C0603C103J5RAC	Kemet
C3	0.1 $\mu\text{F}$ Chip Capacitor	C0603C104J5RAC	Kemet
C4	1 $\mu\text{F}$ Chip Capacitor	C0603C105J5RAC	Kemet
L1	470 nH Chip Inductor	BK2125HM471-T	Taiyo Yuden
R1	0 $\Omega$ , 1/10 W Chip Resistor	CRCW06030000FKEA	Vishay

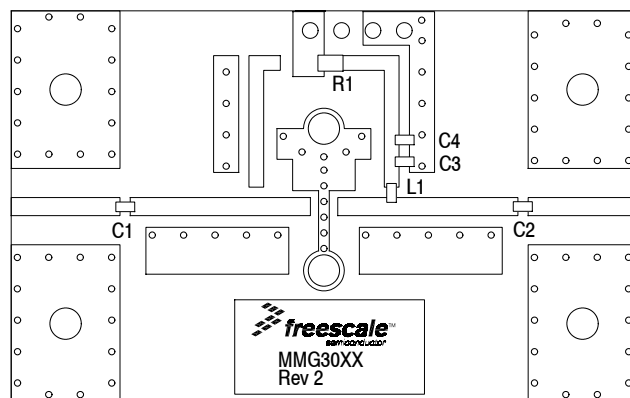
## 50 OHM APPLICATION CIRCUIT: 800-3600 MHz



**Figure 17. 50 Ohm Test Circuit Schematic**



**Figure 18. S21, S11 and S22 versus Frequency**



**Figure 19. 50 Ohm Test Circuit Component Layout**

**Table 9. 50 Ohm Test Circuit Component Designations and Values**

Part	Description	Part Number	Manufacturer
C1, C2	150 pF Chip Capacitors	C0603C151J5RAC	Kemet
C3	0.1 $\mu$ F Chip Capacitor	C0603C104J5RAC	Kemet
C4	1 $\mu$ F Chip Capacitor	C0603C105J5RAC	Kemet
L1	56 nH Chip Inductor	HK160856NJ-T	Taiyo Yuden
R1	0 $\Omega$ , 1/10 W Chip Resistor	CRCW06030000FKEA	Vishay

## 50 OHM TYPICAL CHARACTERISTICS

**Table 10. Common Emitter S-Parameters** ( $V_{CC} = 5 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ , 50 Ohm System)

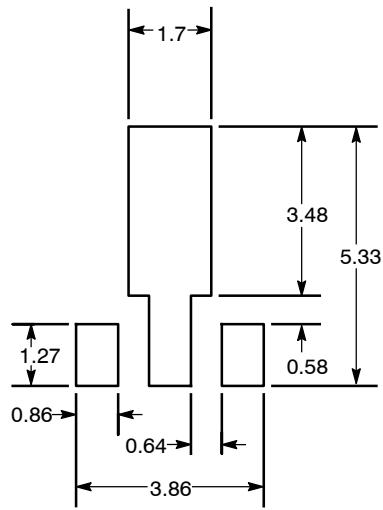
f MHz	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>	
	S <sub>11</sub>	∠ φ	S <sub>21</sub>	∠ φ	S <sub>12</sub>	∠ φ	S <sub>22</sub>	∠ φ
200	0.28	174.23	6.17	171.48	0.08	-2.66	0.06	-43.26
250	0.28	172.92	6.16	169.36	0.08	-3.32	0.07	-50.81
300	0.27	171.92	6.15	167.25	0.08	-3.93	0.08	-56.75
350	0.27	170.57	6.14	165.15	0.08	-4.60	0.09	-62.45
400	0.27	169.49	6.12	163.07	0.08	-5.22	0.09	-67.13
450	0.26	168.53	6.11	160.97	0.08	-5.85	0.10	-71.09
500	0.26	167.16	6.10	158.87	0.08	-6.50	0.11	-74.88
550	0.26	165.92	6.08	156.78	0.08	-7.14	0.12	-77.99
600	0.26	164.77	6.06	154.73	0.08	-7.76	0.13	-81.75
650	0.26	163.38	6.05	152.65	0.08	-8.41	0.14	-85.06
700	0.25	162.57	6.03	150.58	0.08	-9.03	0.14	-88.16
750	0.25	161.36	6.01	148.53	0.08	-9.64	0.15	-91.28
800	0.25	160.35	5.99	146.50	0.08	-10.26	0.16	-93.96
850	0.25	159.29	5.97	144.45	0.08	-10.88	0.17	-96.90
900	0.25	158.03	5.95	142.41	0.08	-11.52	0.18	-99.99
950	0.24	157.14	5.93	140.38	0.08	-12.14	0.18	-102.70
1000	0.24	156.02	5.91	138.38	0.08	-12.78	0.19	-105.47
1050	0.24	154.89	5.88	136.37	0.08	-13.38	0.20	-108.27
1150	0.24	153.09	5.83	132.34	0.08	-14.64	0.21	-114.23
1200	0.24	152.30	5.80	130.37	0.08	-15.28	0.22	-117.17
1250	0.24	151.41	5.77	128.39	0.08	-15.94	0.22	-120.26
1300	0.24	150.63	5.75	126.41	0.08	-16.57	0.23	-123.42
1350	0.24	150.09	5.72	124.46	0.08	-17.17	0.24	-126.34
1400	0.24	149.52	5.69	122.50	0.08	-17.81	0.24	-129.61
1450	0.24	149.15	5.67	120.54	0.08	-18.46	0.25	-132.32
1500	0.23	148.71	5.65	118.61	0.08	-19.07	0.26	-134.63
1550	0.23	147.76	5.62	116.65	0.08	-19.73	0.26	-136.77
1600	0.23	146.51	5.60	114.72	0.08	-20.39	0.27	-138.90
1650	0.23	145.11	5.57	112.79	0.08	-21.04	0.28	-141.13
1900	0.23	138.41	5.41	103.23	0.08	-24.38	0.31	-152.46
2150	0.24	132.77	5.23	93.77	0.08	-27.79	0.35	-163.83
2400	0.25	128.41	5.05	84.48	0.08	-31.33	0.38	-175.54
2650	0.26	124.16	4.87	75.21	0.08	-35.09	0.40	172.45
2900	0.28	119.27	4.69	66.04	0.08	-39.03	0.43	161.50
2950	0.28	118.39	4.65	64.24	0.08	-39.86	0.44	159.35
3000	0.28	117.49	4.62	62.43	0.09	-40.65	0.44	157.23
3050	0.28	116.75	4.59	60.59	0.09	-41.48	0.45	154.83
3100	0.29	116.03	4.55	58.77	0.09	-42.33	0.46	152.37
3150	0.29	115.21	4.52	56.97	0.09	-43.16	0.46	150.02
3200	0.29	114.41	4.48	55.15	0.09	-44.01	0.47	147.68
3250	0.29	113.69	4.44	53.36	0.09	-44.83	0.48	145.58
3300	0.29	112.97	4.41	51.59	0.09	-45.67	0.48	143.48
3350	0.29	112.24	4.37	49.84	0.09	-46.48	0.49	141.43

(continued)

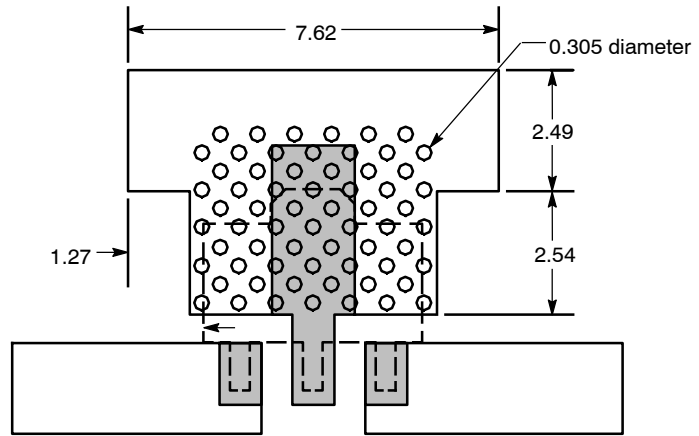
## 50 OHM TYPICAL CHARACTERISTICS

**Table 10. Common Emitter S-Parameters** ( $V_{CC} = 5 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ , 50 Ohm System) (continued)

f MHz	S <sub>11</sub>		S <sub>21</sub>		S <sub>12</sub>		S <sub>22</sub>	
	S <sub>11</sub>	∠ φ	S <sub>21</sub>	∠ φ	S <sub>12</sub>	∠ φ	S <sub>22</sub>	∠ φ
3400	0.29	111.50	4.34	48.07	0.09	-47.31	0.49	139.46
3450	0.29	110.37	4.30	45.96	0.09	-48.32	0.50	137.08
3500	0.29	109.50	4.27	44.53	0.09	-49.01	0.50	135.57
3550	0.29	108.57	4.23	42.83	0.09	-49.82	0.51	133.81
3600	0.29	107.57	4.20	41.14	0.09	-50.64	0.52	132.08



Recommended Solder Stencil

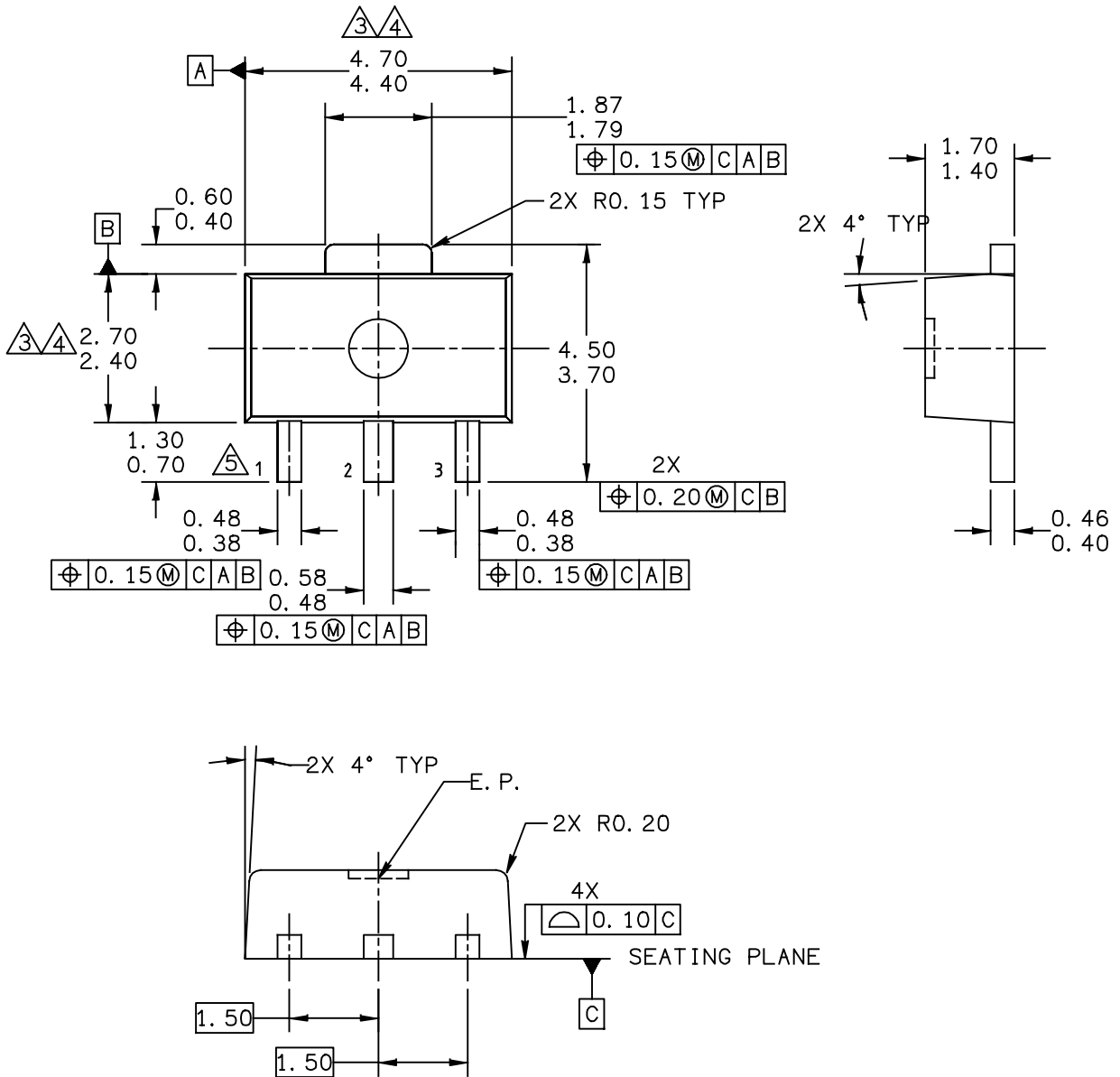


NOTES:

1. THERMAL AND RF GROUNDING CONSIDERATIONS SHOULD BE USED IN PCB LAYOUT DESIGN.
2. DEPENDING ON PCB DESIGN RULES, AS MANY VIAS AS POSSIBLE SHOULD BE PLACED ON THE LANDING PATTERN.
3. IF VIAS CANNOT BE PLACED ON THE LANDING PATTERN, THEN AS MANY VIAS AS POSSIBLE SHOULD BE PLACED AS CLOSE TO THE LANDING PATTERN AS POSSIBLE FOR OPTIMAL THERMAL AND RF PERFORMANCE.
4. RECOMMENDED VIA PATTERN SHOWN HAS 0.381 x 0.762 MM PITCH.

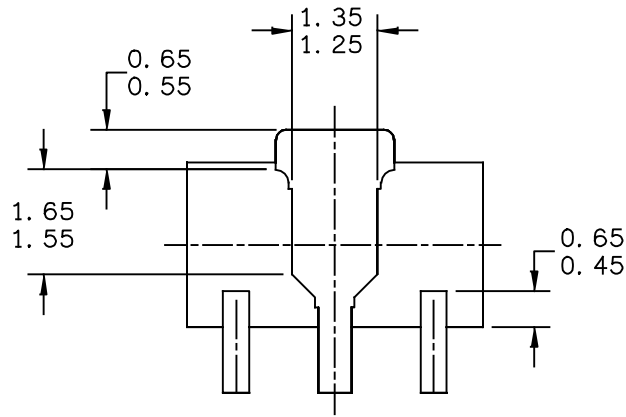
Figure 20. Recommended Mounting Configuration

## PACKAGE DIMENSIONS



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TITLE: SOT-89, 4 LEAD, 4.5 X 2.5 PKG, 1.5 MM PITCH		DOCUMENT NO: 98ASA10586D	REV: D
		CASE NUMBER: 1514-02	27 JUN 2007
		STANDARD: NON-JEDEC	

MMG3015NT1



BOTTOM VIEW

CASE STYLE:

STYLE 1:  
 PIN 1. RF INPUT  
 PIN 2. GROUND  
 PIN 3. RF OUTPUT

STYLE 2:  
 PIN 1. GATE  
 PIN 2. SOURCE  
 PIN 3. DRAIN

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TITLE: SOT-89, 4 LEAD, 4.5 X 2.5 PKG, 1.5 MM PITCH	DOCUMENT NO: 98ASA10586D	REV: D	
	CASE NUMBER: 1514-02	27 JUN 2007	
	STANDARD: NON-JEDEC		

NOTES:

1 DIMENSIONING AND TOLERANCING PER ASME Y14.5M – 1994.

2 ALL DIMENSIONS ARE IN MILLIMETERS.

3 DIMENSIONS DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.5mm PER END. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.5 mm PER SIDE.

4 DIMENSION ARE DETERMINED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

5 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

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	CASE NUMBER: 1514-02	27 JUN 2007	
	STANDARD: NON-JEDEC		

## PRODUCT DOCUMENTATION, SOFTWARE AND TOOLS

Refer to the following documents, software and tools to aid your design process.

### Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers
- AN3100: General Purpose Amplifier and MMIC Biasing

### Software

- .s2p File

### Development Tools

- Printed Circuit Boards

For Software and Tools, do a Part Number search at <http://www.freescale.com>, and select the “Part Number” link. Go to the Software & Tools tab on the part’s Product Summary page to download the respective tool.

## REVISION HISTORY

The following table summarizes revisions to this document.

Revision	Date	Description
0	Aug. 2007	<ul style="list-style-type: none"><li>• Initial Release of Data Sheet</li></ul>
1	Apr. 2008	<ul style="list-style-type: none"><li>• Removed Footnote 2, Continuous voltage and current applied to device, from Table 2, Maximum Ratings, p. 1</li><li>• Corrected Fig. 13, Single-Carrier W-CDMA Adjacent Channel Power Ratio versus Output Power y-axis (ACPR) unit of measure to dBc, p. 5</li><li>• Updated Part Numbers in Tables 8, 9, Component Designations and Values, to latest RoHS compliant part numbers, p. 6, 7</li></ul>
2	Feb. 2012	<ul style="list-style-type: none"><li>• Corrected temperature at which Theta<sub>JC</sub> is measured from 25°C to 95°C and added “no RF applied” to Thermal Characteristics table to indicate that thermal characterization is performed under DC test with no RF signal applied, p. 1</li><li>• Table 6, ESD Protection Characterization, removed the word “Minimum” after the ESD class rating. ESD ratings are characterized during new product development but are not 100% tested during production. ESD ratings provided in the data sheet are intended to be used as a guideline when handling ESD sensitive devices, p. 3</li><li>• Removed I<sub>CC</sub> bias callout from applicable graphs and Table 10, Common Emitter S-Parameters heading as bias is not a controlled value, p. 4-9</li><li>• Added .s2p File availability to Product Software and Printed Circuit Boards to Development Tools, p. 14</li></ul>

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